NSN 5961-00-168-4261

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View Online at https://aerobasegroup.com/nsn/5961-00-168-4261 **Inclosure Material:** Plastic and ceramic **Overall Length:** 0.695 inches **Overall Height:** 1.475 inches **Overall Width:** 0.935 inches **End Application:** Helicopter, utillity search and recovery uh-1n **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 breakdown voltage, collector-to-base, emitter open and 33.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 27.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80063-sm-a-597849 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc

N/a

4 ribbon Shelf Life:

Unit Of Measure:

Terminal Type And Quantity:

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No

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